

20 PWRDOWN

19 V_{CC}

18 GND

17 DOUT1

16 DOUT2

15 DOUT3

14 RIN1

13 RIN2

11 ROUT1

12 V_L

PW OR DW PACKAGE

TOP VIEW

C1+

V+ 2

C1-3

C2+ 4

C2-5

V-[6

DIN17

DIN2₈

DIN3 9

ROUT2 10

FEATURES

- V_L Pin for Compatibility With Mixed-Voltage Systems Down to 1.8 V on Logic Side
- Enhanced ESD Protection on RIN Inputs and DOUT Outputs
 - ±15-kV Human-Body Model
 - ±15-kV IEC 61000-4-2, Air-Gap Discharge
 - ±8-kV IEC 61000-4-2, Contact Discharge
- Low 300-µA Supply Current
- Specified 250-kbps Data Rate
- 1-µA Low-Power Shutdown
- Meets EIA/TIA-232 Specifications Down to 3 V

APPLICATIONS

- Hand-Held Equipment
- PDAs
- Cell Phones
- Battery-Powered Equipment
- Data Cables

DESCRIPTION/ORDERING INFORMATION

The MAX3386E is a three-driver and two-receiver RS-232 interface device, with split supply pins for mixed-signal operations. All RS-232 inputs and outputs are protected to ± 15 kV using the IEC 61000-4-2 Air-Gap Discharge method, ± 8 kV using the IEC 61000-4-2 Contact Discharge method, and ± 15 kV using the Human-Body Model.

The charge pump requires only four small 0.1-µF capacitors for operation from a 3.3-V supply. The MAX3386E is capable of running at data rates up to 250 kbps, while maintaining RS-232-compliant output levels.

The MAX3386E has a unique V_L pin that allows operation in mixed-logic voltage systems. Both driver in (DIN) and receiver out (ROUT) logic levels are pin programmable through the V_L pin. The MAX3386E is available in a space-saving thin shrink small-outline package (TSSOP).

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
000 to 7000	TSSOP – PW	MAX3386ECPWR	MP386EC
	SOIC – DW	MAX3386ECDW	MAX3386EC
40°C to 95°C	TSSOP – PW	MAX3386EIPWR	MP386EI
	SOIC – DW	MAX3386EIDW	MAX3386EI

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

PWRDWN	DRIVER OUTPUTS	RECEIVER OUTPUTS	CHARGE PUMP
L	High-Z	High-Z	Inactive
Н	Active	Active	Active

TRUTH TABLE (SHUTDOWN FUNCTION)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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TERMINAL FUNCTIONS

TERMINAL		DESCRIPTION	
NAME	NO.	DESCRIPTION	
C1+	1	Positive terminal of the voltage-doubler charge-pump capacitor	
V+	2	5.5-V supply generated by the charge pump	
C1–	3	Negative terminal of the voltage-doubler charge-pump capacitor	
C2+	4	Positive terminal of the inverting charge-pump capacitor	
C2-	5	Negative terminal of the inverting charge-pump capacitor	
V–	6	-5.5-V supply generated by the charge pump	
DIN1 DIN2 DIN3	7 8 9	Driver inputs	
ROUT2 ROUT1	10 11	Receiver outputs. Swing between 0 and V_L .	
VL	12	Logic-level supply. All CMOS inputs and outputs are referenced to this supply.	
RIN2 RIN1	13 14	RS-232 receiver inputs	
DOUT3 DOUT2 DOUT1	15 16 17	RS-232 driver outputs	
GND	18	Ground	
V _{CC}	19	3-V to 5.5-V supply voltage	
PWRDWN	20	Powerdown input L = Powerdown H = Normal operation	

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
	V _{CC} to GND		-0.3	6	V
	V _L to GND		-0.3	V _{CC} + 0.3	V
	V+ to GND	to GND to GND + V- ⁽²⁾ DIN. <u>PWRDWN</u> to GND		7	V
	V- to GND		0.3	- 7	V
	V+ + V- ⁽²⁾			13	V
V		DIN, PWRDWN to GND	-0.3	6	V
VI	Input voltage	RIN to GND		±25	V
V	Output welte as	DOUT to GND		±25 ±13.2	V
vo	Output voltage	ROUT	-0.3	V _L + 0.3	v
	Short-circuit duration DOUT to GND			Continuous	
	Continuous power dissipation	$T_A = 70^{\circ}C$, 20-pin TSSOP (derate 7 mW/°C above 70°C)		559	mW
TJ	Junction temperature			150	°C
T _{stg}	Storage temperature range		-65	150	°C
	Lead temperature (soldering, 10 s)			300	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

(2) V+ and V- can have maximum magnitudes of 7 V, but their absolute difference cannot exceed 13 V.

Recommended Operating Conditions

				MIN	MAX	UNIT
V_{CC}	Supply voltage			3	5.5	V
V_{L}	Supply voltage			1.65	V _{CC}	V
			$V_{L} = 3 V \text{ or } 5.5 V$		0.8	
	Input logic threshold low	DIN, PWRDWN	$V_{L} = 2.3 V$		0.6	V
			V _L = 1.65 V		0.5	
			$V_{L} = 5.5 V$	2.4		V
			$V_L = 3 V$	2.0		
	input logic threshold high		V _L = 2.7 V	1.4		
			V _L = 1.95 V	0.9		
			MAX3386ECPWR	0	70	°C
	Operating temperature	MAX3386EIPWR		-40	85	C
	Receiver input voltage			-25	25	V

Electrical Characteristics

over operating free-air temperature range, $V_{CC} = V_L = 3 \text{ V}$ to 5.5 V, C1–C4 = 0.1 μ F (tested at 3.3 V \pm 10%), C1 = 0.047 μ F, C2–C4 = 0.33 μ F (tested at 5 V \pm 10%) (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
DC Characteristics (V _{CC} = 3	.3 V or 5 V, T _A = 25°C)	MIN TYP ⁽¹⁾ MAX U 1 10 0.3 1 1			
Powerdown supply current	PWRDWN = GND, All inputs at V _{CC} or GND		1	10	μΑ
Supply current	$\overline{PWRDWN} = V_{CC}$, No load		0.3	1	mA

(1) Typical values are at $V_{CC} = V_L = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

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TEXAS INSTRUMENTS www.ti.com

ESD Protection

PARAMETER	TEST CONDITIONS	TYP	UNIT
	Human-Body Model	±15	
RIN, DOUT	IEC 61000-4-2 Air-Gap Discharge	±15	kV
	IEC 61000-4-2 Contact Discharge	±8	

RECEIVER SECTION

Electrical Characteristics

over operating free-air temperature range, V_{CC} = V_L = 3 V to 5.5 V, C1–C4 = 0.1 μ F (tested at 3.3 V ± 10%), C1 = 0.047 μ F, C2–C4 = 0.33 μ F (tested at 5 V ± 10%), T_A = T_{MIN} to T_{MAX} (unless otherwise noted)

	PARAMETER	TEST CONDI	TIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
I _{off}	Output leakage current	ROUT, receivers disabled			±0.05	±10	μA
V _{OL}	Output voltage low	I _{OUT} = 1.6 mA				0.4	V
V _{OH}	Output voltage high	$I_{OUT} = -1 \text{ mA}$		$V_{L} - 0.6$	$V_{L} - 0.1$		V
V	Input throopold low	T 2500	$V_L = 5 V$	0.8	1.2		N/
V _{IT} -	Input threshold low	$I_{A} = 25^{\circ}C$	$V_{L} = 3.3 V$	0.6	1.5		v
V	Input throshold high	T _ 25°C	$V_L = 5 V$		1.8	2.4	V
VIT+	input threshold high	$I_A = 25^{\circ}C$	$V_{L} = 3.3 V$		1.5	2.4	v
V _{hys}	Input hysteresis				0.5		V
	Input resistance	$T_A = 25^{\circ}C$		3	5	7	kΩ

(1) Typical values are at V_{CC} = V_L = 3.3 V, T_A = 25°C

Switching Characteristics

over operating free-air temperature range, $V_{CC} = V_L = 3 \text{ V}$ to 5.5 V, C1–C4 = 0.1 μ F (tested at 3.3 V \pm 10%), C1 = 0.047 μ F, C2–C4 = 0.33 μ F (tested at 5 V \pm 10%), T_A = T_{MIN} to T_{MAX} (unless otherwise noted)

PARAMETER		TEST CONDITIONS	TYP ⁽¹⁾	UNIT
t _{PHL}	Passiver propagation dolay	Peopliner input to receiver output $C = 150 \text{ pc}$	0.15	
t _{PLH}	Receiver propagation delay	Receiver input to receiver output, $C_L = 150 \text{ pr}$		μs
t _{PHL} – t _{PLH}	Receiver skew		50	ns
t _{en}	Receiver output enable time	From PWRDWN	200	ns
t _{dis}	Receiver output disable time	From PWRDWN	200	ns

(1) Typical values are at $V_{CC} = V_L = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}.$



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DRIVER SECTION

Electrical Characteristics

over operating free-air temperature range, V_{CC} = V_L = 3 V to 5.5 V, C1–C4 = 0.1 μ F (tested at 3.3 V ± 10%), C1 = 0.047 μ F, C2–C4 = 0.33 μ F (tested at 5 V ± 10%), T_A = T_{MIN} to T_{MAX} (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{OH}	Output voltage swing	All driver outputs loaded with 3 k Ω to ground	±5	±5.4		V
r _o	Output resistance	$V_{CC} = V + = V - = 0$, Driver output = $\pm 2 V$	300	10M		Ω
I _{OS}	Output short-circuit current	$V_{T_OUT} = 0$			±60	mA
I _{OZ}	Output leakage current	$V_{T_OUT} = \pm 12$ V, Driver disabled, $V_{CC} = 0$ or 3 V to 5.5 V			±25	μΑ
	Driver input hysteresis				0.5	V
	Input leakage current	DIN, PWRDWN		±0.01	±1	μA

(1) Typical values are at $V_{CC} = V_L = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$

Timing Requirements

over operating free-air temperature range, V_{CC} = V_L = 3 V to 5.5 V, C1–C4 = 0.1 μ F (tested at 3.3 V ± 10%), C1 = 0.047 μ F, C2–C4 = 0.33 μ F (tested at 5 V ± 10%), T_A = T_{MIN} to T_{MAX} (unless otherwise noted)

	PARAMETER			MIN	TYP ⁽¹⁾	MAX	UNIT
	Maximum data rate	$R_L = 3 \text{ k}\Omega, C_L = 1000 \text{ pF}, C_L = 1000 \text{ pF}$	One driver switching	250			kbps
	Time-to-exit powerdown	V _{T_OUT} > 3.7 V	$\begin{array}{c} = 3 \text{ k}\Omega, \text{C}_{\text{L}} = 1000 \text{ pF}, \text{ One driver switching} \\ \hline \text{T_OUT} > 3.7 \text{ V} \\ \hline \text{C}_{\text{C}} = 3.3 \text{ V}, \\ = 25^{\circ}\text{C}, \\ = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega, \\ \text{easured from 3 V} \\ \hline \text{C}_{\text{L}} = 150 \text{ pF to } 1000 \text{ pF} \\ \hline \text{C}_{\text{L}} = 150 \text{ pF to } 2500 \text{ pF} \\ \hline \end{array}$		100		μs
t _{PHL} t _{PLH}	Driver skew ⁽²⁾				100		ns
		$V_{CC} = 3.3 V,$	C _L = 150 pF to 1000 pF	6		30	
	Transition-region T _A = slew rate Meas to -3	$ \begin{array}{l} T_A = 25^\circ C, \\ R_L = 3 \ k\Omega \ to \ 7 \ k\Omega, \\ Measured \ from \ 3 \ V \\ to \ -3 \ V \ or \ -3 \ V \ to \ 3 \ V \end{array} $	$C_{L} = 150 \text{ pF} \text{ to } 2500 \text{ pF}$	4		30	V/µs

(1) Typical values are at $V_{CC} = V_L = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$. (2) Driver skew is measured at the driver zero crosspoint.

ESD Protection

PARAMETER	TEST CONDITIONS	TYP	UNIT
RIN, DOUT	Human-Body Model	±15	
	IEC 61000-4-2 Air-Gap Discharge	±15	kV
	IEC 61000-4-2 Contact Discharge	±8	

MAX3386E RS-232 TRANSCEIVER WITH SPLIT SUPPLY PIN FOR LOGIC SIDE SLLS659A-MAY 2006-REVISED APRIL 2007

APPLICATION INFORMATION



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PARAMETER MEASUREMENT INFORMATION



- NOTES: A. CL includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns, $t_f \le 10$ ns.

Figure 1. Driver Slew Rate



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, Z_{O} = 50 Ω , 50% duty cycle, $t_{f} \le 10$ ns. $t_{f} \le 10$ ns.

Figure 2. Driver Pulse Skew



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns, $t_f \le 10$ ns.

Figure 3. Receiver Propagation Delay Times

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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.

Figure 4. Receiver Enable and Disable Times

V IEXAS NSTRUMENTS

17-Apr-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
MAX3386ECDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386ECDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386ECDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386ECDWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386ECPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386ECPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386ECPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386ECPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386EIDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386EIDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386EIDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386EIDWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386EIPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386EIPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386EIPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3386EIPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)



⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal													
	Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	MAX3386ECDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
	MAX3386ECPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
	MAX3386EIDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
	MAX3386EIPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1



PACKAGE MATERIALS INFORMATION

11-Mar-2008



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MAX3386ECDWR	SOIC	DW	20	2000	346.0	346.0	41.0
MAX3386ECPWR	TSSOP	PW	20	2000	346.0	346.0	33.0
MAX3386EIDWR	SOIC	DW	20	2000	346.0	346.0	41.0
MAX3386EIPWR	TSSOP	PW	20	2000	346.0	346.0	33.0

MECHANICAL DATA

MTSS001C - JANUARY 1995 - REVISED FEBRUARY 1999

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AC.



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